

TLV2422-Q1, TLV2422A-Q1

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

- Qualification in Accordance With AEC-Q100†
- Qualified for Automotive Applications
- Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Output Swing Includes Both Supply Rails
- Extended Common-Mode Input Voltage Range . . . 0 V to 4.5 V (Min) With 5-V Single Supply
- No Phase Inversion
- Low Noise . . . 18 nV/√Hz Typ at f = 1 kHz
- Low Input Offset Voltage
950 μV Max at T_A = 25°C (TLV2422A)
- Low Input Bias Current . . . 1 pA Typ
- Micropower Operation . . . 50 μA Per Channel
- 600-Ω Output Drive

† Contact factory for details. Q100 qualification data available on request.

description

The TLV2422 and TLV2422A are dual low-voltage operational amplifiers from Texas Instruments. The common-mode input voltage range for this device has been extended over the typical CMOS amplifiers making them suitable for a wide range of applications. In addition, the devices do not phase invert when the common-mode input is driven to the supply rails. This satisfies most design requirements without paying a premium for rail-to-rail input performance. They also exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. This family is fully characterized at 3-V and 5-V supplies and is optimized for low-voltage operation. The TLV2422 only requires 50 μA of supply current per channel, making it ideal for battery-powered applications. The TLV2422 also has increased output drive over previous rail-to-rail operational amplifiers and can drive 600-Ω loads for telecom applications.

Other members in the TLV2422 family are the high-power, TLV2442, and low-power, TLV2432, versions.

The TLV2422, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels and low-voltage operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single- or split-supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLV2422A is available with a maximum input offset voltage of 950 μV.

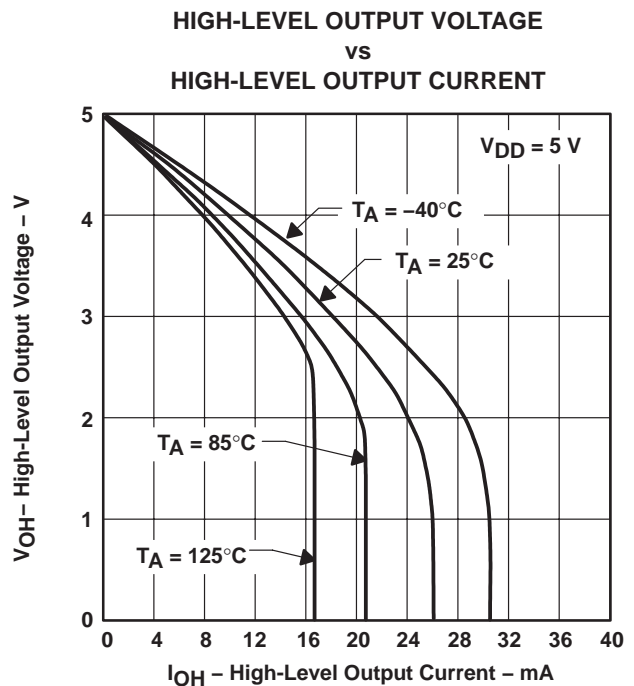
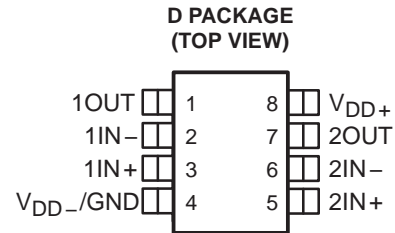


Figure 1



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Advanced LinCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2003, Texas Instruments Incorporated

TLV2422-Q1, TLV2422A-Q1

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

description (continued)

If the design requires single operational amplifiers, see the TI TLV2211/21/31. This is a family of rail-to-rail output operational amplifiers in the SOT-23 package. Their small size and low power consumption, make them ideal for high density, battery-powered equipment.

ORDERING INFORMATION

TA	V _{IO} max AT 25°C	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	950 µV	SOIC (D)	Tape and reel	TLV2422AQDRQ1	2422AQ
	2.5 mV	SOIC (D)	Tape and reel	TLV2422QDRQ1	2422Q1

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

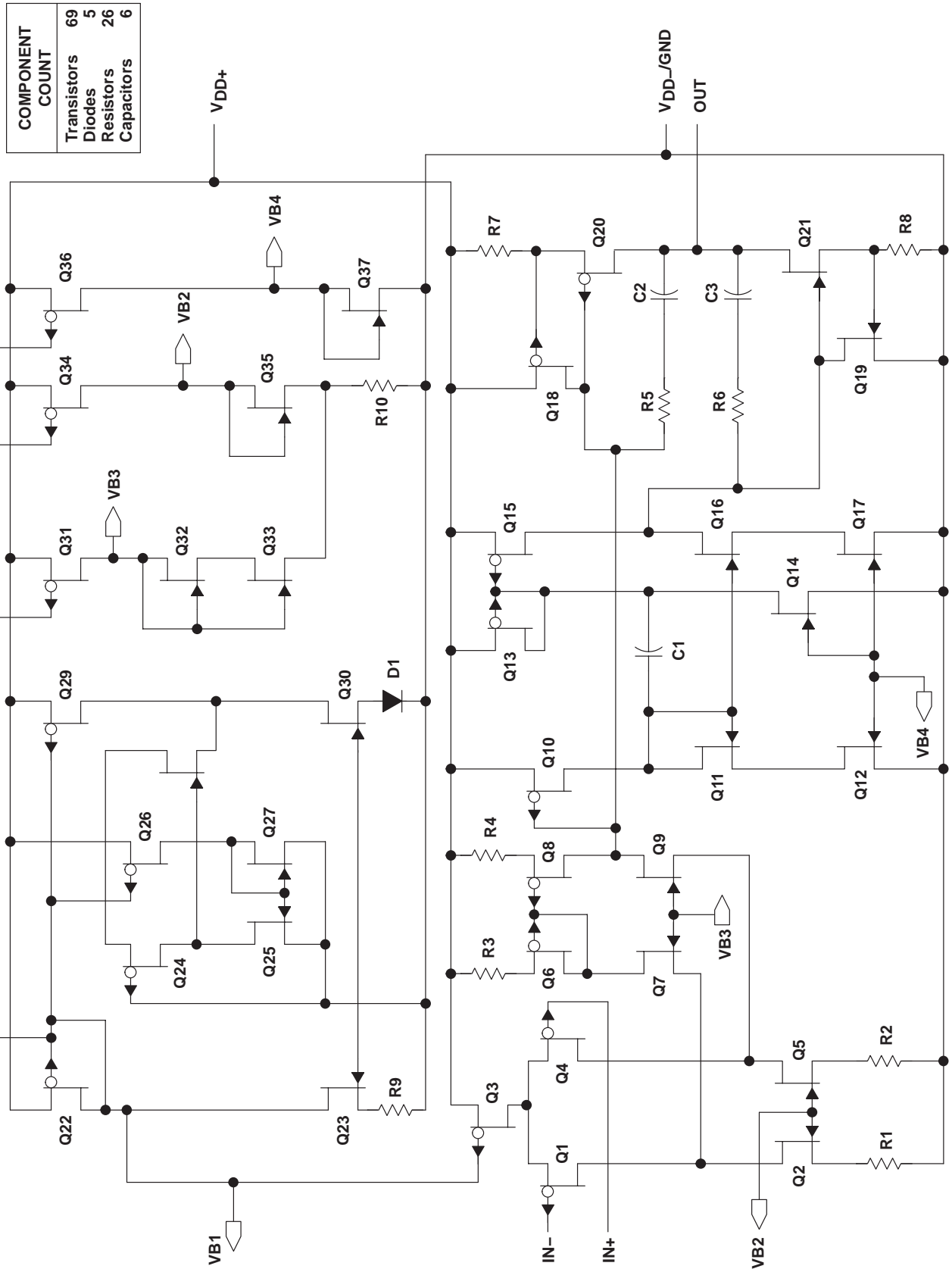


POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

TLV2422-Q1, TLV2422A-Q1
Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT
WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

equivalent schematic (each amplifier)



COMPONENT COUNT	
Transistors	69
Diodes	5
Resistors	26
Capacitors	6

TLV2422-Q1, TLV2422A-Q1
Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT
WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD} (see Note 1)	12 V
Differential input voltage, V_{ID} (see Note 2)	$\pm V_{DD}$
Input voltage, V_I (any input, see Note 1): C and I suffix	–0.3 V to V_{DD}
Input current, I_I (each input)	± 5 mA
Output current, I_O	± 50 mA
Total current into V_{DD+}	± 50 mA
Total current out of V_{DD-}	± 50 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : Q suffix	–40°C to 125°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between V_{DD+} and V_{DD-} .
 2. Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows if input is brought below $V_{DD-} - 0.3$ V.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD\pm}$	2.7	10	V
Input voltage range, V_I	V_{DD-}	$V_{DD+} - 0.8$	V
Common-mode input voltage, V_{IC}	V_{DD-}	$V_{DD+} - 0.8$	V
Operating free-air temperature, T_A	–40	125	°C



TLV2422-Q1, TLV2422A-Q1

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

electrical characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLV2422-Q1			TLV2422A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C		300	2000		300	950	μV
		Full range			2500			1800	
α_{VIO} Temperature coefficient of input offset voltage		Full range		2			2	$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, V_O = 0, V_{DD} \pm = \pm 1.5\text{ V}, R_S = 50\ \Omega$	25°C		0.003			0.003	$\mu\text{V}/\text{mo}$	
I_{IO} Input offset current		25°C		0.5	60		0.5	60	pA
		Full range			150			150	
I_{IB} Input bias current		25°C		1	60		1	60	pA
		Full range			300			300	
V_{ICR} Common-mode input voltage range	$ V_{IO} \leq 5\text{ mV}, R_S = 50\ \Omega$	25°C	0 to 2.5	-0.25 to 2.75		0 to 2.5	-0.25 to 2.75	V	
		Full range	0 to 2.2			0 to 2.2			
V_{OH} High-level output voltage	$I_{OH} = -100\ \mu\text{A}$	25°C		2.97			2.97	V	
	$I_{OH} = -500\ \mu\text{A}$	25°C		2.75			2.75		
		Full range		2.5			2.5		
V_{OL} Low-level output voltage	$V_{IC} = 0, I_{OL} = 100\ \mu\text{A}$	25°C		0.05			0.05	V	
	$V_{IC} = 0, I_{OL} = 250\ \mu\text{A}$	25°C		0.2			0.2		
		Full range			0.5				0.5
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 1.5\text{ V}, V_O = 1\text{ V to } 2\text{ V}$	$R_L = 10\text{ k}\Omega$ ‡	25°C	6	10		6	10	V/mV
		$R_L = 1\text{ M}\Omega$ ‡	Full range		2			2	
			25°C		700			700	
$r_{i(d)}$ Differential input resistance		25°C		10^{12}			10^{12}	Ω	
$r_{i(c)}$ Common-mode input resistance		25°C		10^{12}			10^{12}	Ω	
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C		8			8	pF	
z_o Closed-loop output impedance	$f = 100\text{ kHz}, A_V = 10$	25°C		130			130	Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}\text{ min}, V_O = 1.5\text{ V}, R_S = 50\ \Omega$	25°C		70	83		70	83	dB
		Full range		70			70		
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to } 8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C		80	95		80	95	dB
		Full range		80			80		
I_{DD} Supply current	$V_O = 1.5\text{ V}, \text{ No load}$	25°C		100	150		100	150	μA
		Full range			175			175	

† Full range is -40°C to 125°C for Q level part.

‡ Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLV2422-Q1, TLV2422A-Q1
Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT
WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

operating characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$

PARAMETER		TEST CONDITIONS		T_A †	TLV2422-Q1, TLV2422A-Q1			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	$V_O = 1.1\text{ V to }1.9\text{ V},$ $C_L = 100\text{ pF}‡$	$R_L = 10\text{ k}\Omega‡$	25°C	0.01	0.02	V/ μs	
				Full range	0.008			
V_n	Equivalent input noise voltage	$f = 10\text{ Hz}$		25°C	100		nV/ $\sqrt{\text{Hz}}$	
		$f = 1\text{ kHz}$		25°C	23			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		25°C	2.7		μV	
		$f = 0.1\text{ Hz to }10\text{ Hz}$		25°C	4			
I_n	Equivalent input noise current			25°C	0.6		fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V},$ $f = 1\text{ kHz},$ $R_L = 10\text{ k}\Omega‡$	$A_V = 1$	25°C	0.25%			
			$A_V = 10$		1.8%			
	Gain-bandwidth product	$f = 10\text{ kHz},$ $C_L = 100\text{ pF}‡$	$R_L = 10\text{ k}\Omega‡$	25°C	46		kHz	
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 1\text{ V},$ $R_L = 10\text{ k}\Omega‡$	$A_V = 1,$ $C_L = 100\text{ pF}‡$	25°C	8.3		kHz	
t_s	Settling time	$A_V = -1,$ Step = 0.5 V to 2.5 V, $R_L = 10\text{ k}\Omega‡$, $C_L = 100\text{ pF}‡$	To 0.1%	25°C	8.6		μs	
			To 0.01%		16			
ϕ_m	Phase margin at unity gain			25°C	62°			
	Gain margin	$R_L = 10\text{ k}\Omega‡$	$C_L = 100\text{ pF}‡$	25°C	11		dB	

† Full range is -40°C to 125°C for Q level part.

‡ Referenced to 1.5 V

TLV2422-Q1, TLV2422A-Q1

Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT

WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLV2422-Q1			TLV2422A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, V_{DD} \pm = \pm 2.5\text{ V}, R_S = 50\ \Omega$	25°C	300	2000		300	950	μV	
		Full range			2500		1800		
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage		Full range		2			2	$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C		0.003			0.003	$\mu\text{V}/\text{mo}$	
I_{IO} Input offset current		25°C		0.5	60		0.5	60	pA
		Full range			150			150	
I_{IB} Input bias current	25°C		1	60		1	60	pA	
	Full range			300			300		
V_{ICR} Common-mode input voltage range	$ V_{IO} \leq 5\text{ mV}, R_S = 50\ \Omega$	25°C	0 to 4.5	-0.25 to 4.75		0 to 4.5	-0.25 to 4.75	V	
		Full range	0 to 4.2			0 to 4.2			
V_{OH} High-level output voltage	$I_{OH} = -100\ \mu\text{A}$ $I_{OH} = -1\text{ mA}$	25°C		4.97			4.97	V	
		25°C		4.75			4.75		
		Full range		4.5			4.5		
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}, I_{OL} = 100\ \mu\text{A}$ $V_{IC} = 2.5\text{ V}, I_{OL} = 500\ \mu\text{A}$	25°C		0.04			0.04	V	
		25°C		0.15			0.15		
		Full range			0.5				0.5
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}, V_O = 1\text{ V to }4\text{ V}$	25°C	$R_L = 10\text{ k}\Omega^\ddagger$			8	12	V/mV	
			$R_L = 1\text{ M}\Omega^\ddagger$			8	12		
		Full range		3			3		
$r_{i(d)}$ Differential input resistance		25°C		10^{12}			10^{12}	Ω	
$r_{i(c)}$ Common-mode input resistance		25°C		10^{12}			10^{12}	Ω	
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C		8			8	pF	
z_o Closed-loop output impedance	$f = 100\text{ kHz}, A_V = 10$	25°C		130			130	Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}\text{ min}, V_O = 2.5\text{ V}, R_S = 50\ \Omega$	25°C	70	90		70	90	dB	
		Full range		70			70		
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 4.4\text{ V to }8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95		80	95	dB	
		Full range		80			80		
I_{DD} Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C	100	150		100	150	μA	
		Full range			175				175

† Full range is -40°C to 125°C for Q level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at $T_A = 150^\circ\text{C}$ extrapolated to $T_A = 25^\circ\text{C}$ using the Arrhenius equation and assuming an activation energy of 0.96 eV.



TLV2422-Q1, TLV2422A-Q1
Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT
WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

operating characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$

PARAMETER		TEST CONDITIONS		T_A †	TLV2422-Q1, TLV2422A-Q1			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	$V_O = 1.5\text{ V to }3.5\text{ V},$ $C_L = 100\text{ pF}‡$	$R_L = 10\text{ k}\Omega‡$	25°C	0.01	0.02	V/ μ s	
				Full range	0.008			
V_n	Equivalent input noise voltage			25°C	100		nV/ $\sqrt{\text{Hz}}$	
				25°C	18			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage			25°C	1.9		μ V	
				25°C	2.8			
I_n	Equivalent input noise current			25°C	0.6		fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_O = 1.5\text{ V to }3.5\text{ V},$ $f = 1\text{ kHz},$ $R_L = 10\text{ k}\Omega‡$		25°C	$A_V = 1$	0.24%		
					$A_V = 10$	1.7%		
Gain-bandwidth product		$f = 10\text{ kHz},$ $C_L = 100\text{ pF}‡$	$R_L = 10\text{ k}\Omega‡$	25°C	52		kHz	
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V},$ $R_L = 10\text{ k}\Omega‡$	$A_V = 1,$ $C_L = 100\text{ pF}‡$	25°C	5.3		kHz	
t_s	Settling time	$A_V = -1,$ Step = 1.5 V to 3.5 V, $R_L = 10\text{ k}\Omega‡,$ $C_L = 100\text{ pF}‡$		25°C	To 0.1%	8.5		μ s
					To 0.01%	15.5		
ϕ_m	Phase margin at unity gain			25°C	66°			
	Gain margin			$R_L = 10\text{ k}\Omega‡,$	$C_L = 100\text{ pF}‡$	25°C		11

† Full range is -40°C to 125°C for Q level part.

‡ Referenced to 2.5 V

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution vs Common-mode input voltage	2,3 4,5
α_{VIO}	Input offset voltage temperature coefficient	Distribution	6,7
I_{IB}/I_{IO}	Input bias and input offset currents	vs Free-air temperature	8
V_{OH}	High-level output voltage	vs High-level output current	9,11
V_{OL}	Low-level output voltage	vs Low-level output current	10,12
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	13
I_{OS}	Short-circuit output current	vs Supply voltage	14
		vs Free-air temperature	15
V_{ID}	Differential input voltage	vs Output voltage	16,17
		Differential gain	vs Load resistance
A_{VD}	Large-signal differential voltage amplification Differential voltage amplification	vs Frequency	19,20
		vs Free-air temperature	21,22
z_o	Output impedance	vs Frequency	23,24
CMRR	Common-mode rejection ratio	vs Frequency	25
		vs Free-air temperature	26
k_{SVR}	Supply-voltage rejection ratio	vs Frequency	27,28
		vs Free-air temperature	29
I_{DD}	Supply current	vs Supply voltage	30
SR	Slew rate	vs Load capacitance	31
		vs Free-air temperature	32
V_O	Inverting large-signal pulse response		33,34
V_O	Voltage-follower large-signal pulse response		35,36
V_O	Inverting small-signal pulse response		37,38
V_O	Voltage-follower small-signal pulse response		39,40
V_n	Equivalent input noise voltage	vs Frequency	41, 42
		Noise voltage (referred to input)	Over a 10-second period
THD + N	Total harmonic distortion plus noise	vs Frequency	44,45
		Gain-bandwidth product	vs Supply voltage vs Free-air temperature
ϕ_m	Phase margin	vs Frequency	19,20
		vs Load capacitance	48
	Gain margin	vs Load capacitance	49
B_1	Unity-gain bandwidth	vs Load capacitance	50

TYPICAL CHARACTERISTICS

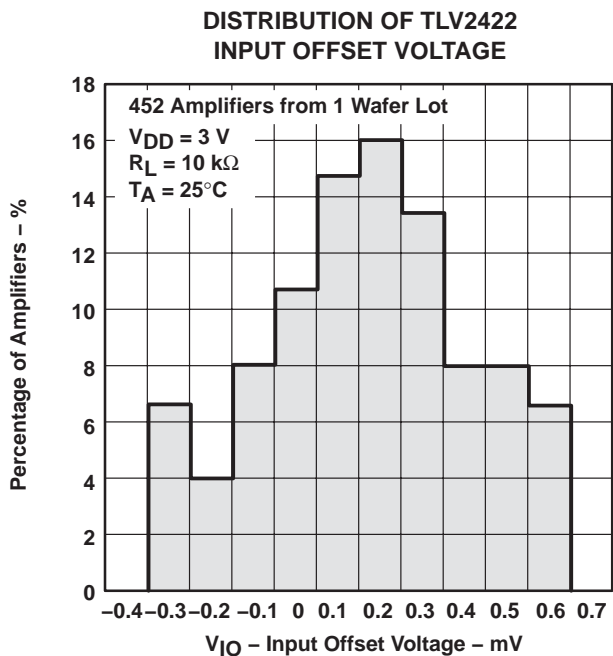


Figure 2

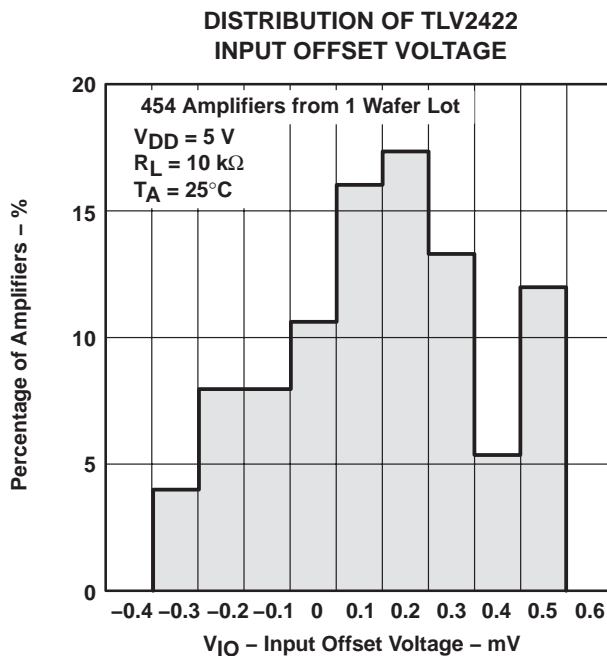


Figure 3

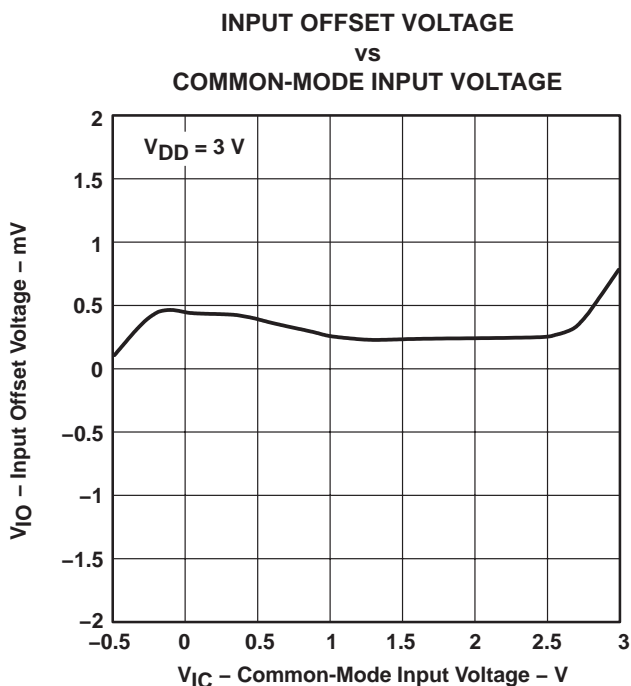


Figure 4

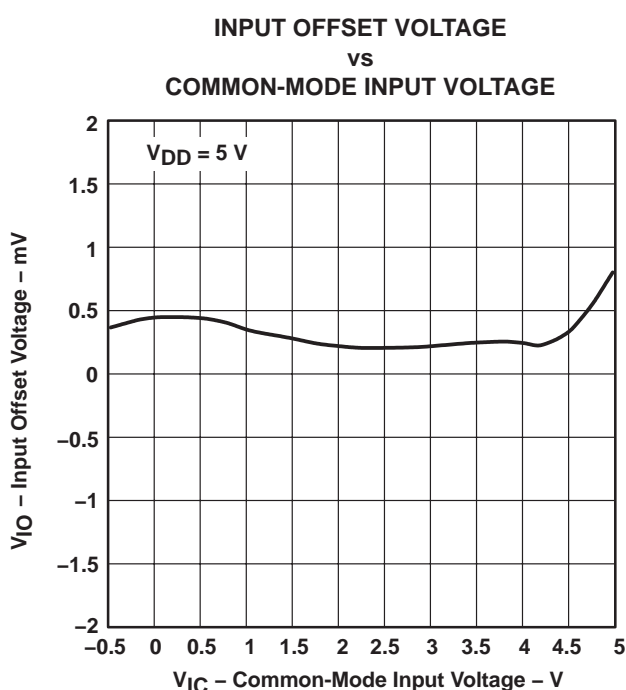


Figure 5

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLV2422 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

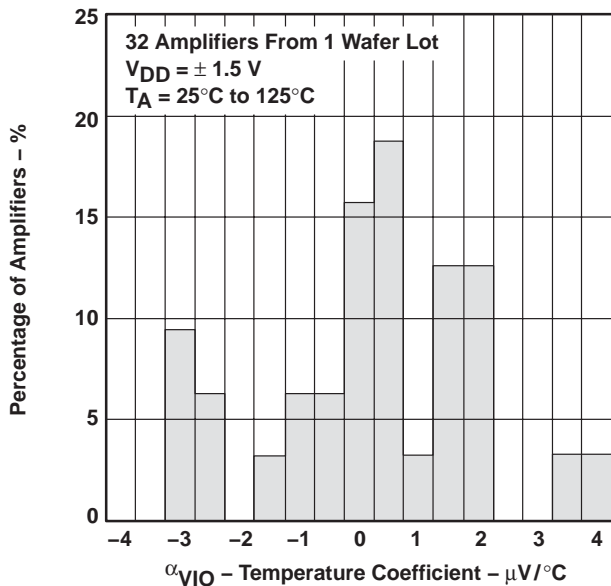


Figure 6

DISTRIBUTION OF TLV2422 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

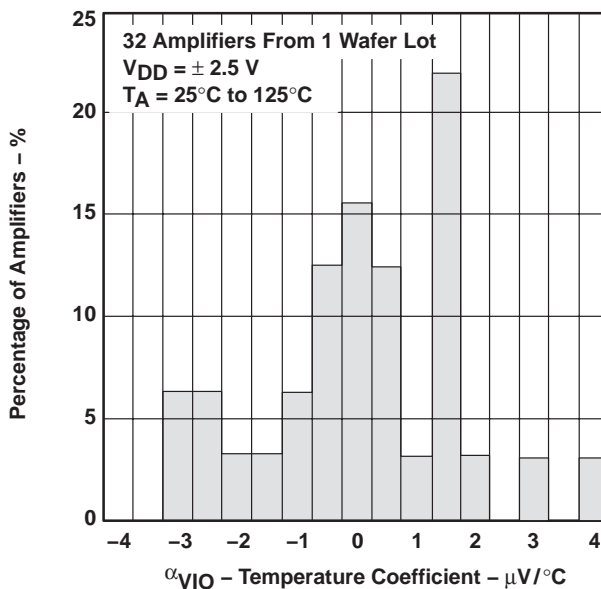


Figure 7

INPUT BIAS AND INPUT OFFSET CURRENTS vs FREE-AIR TEMPERATURE

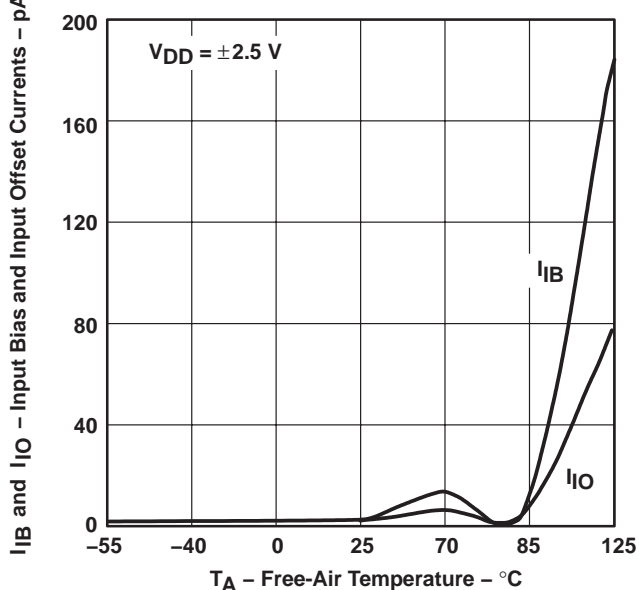


Figure 8

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

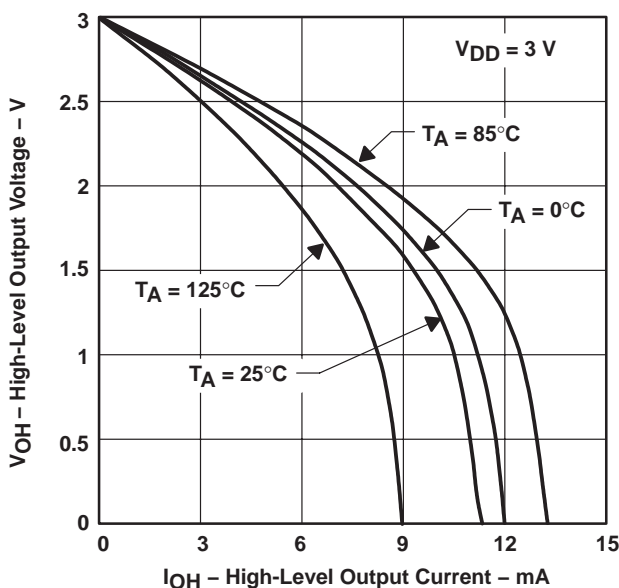


Figure 9

TYPICAL CHARACTERISTICS

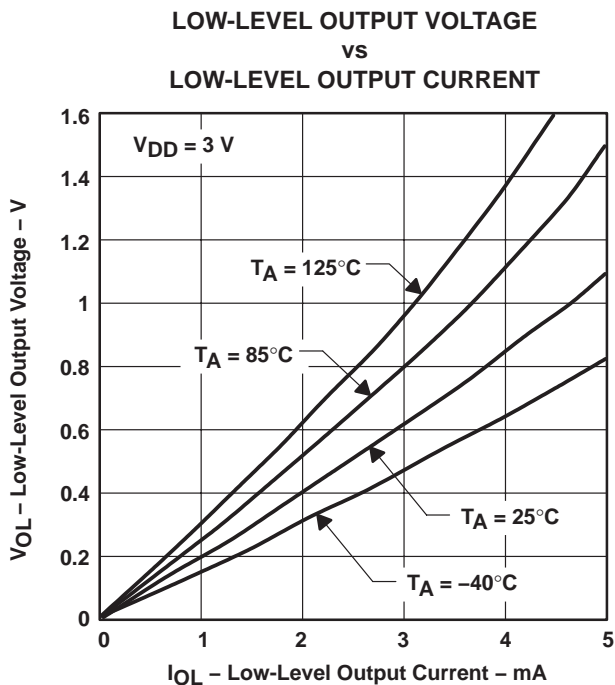


Figure 10

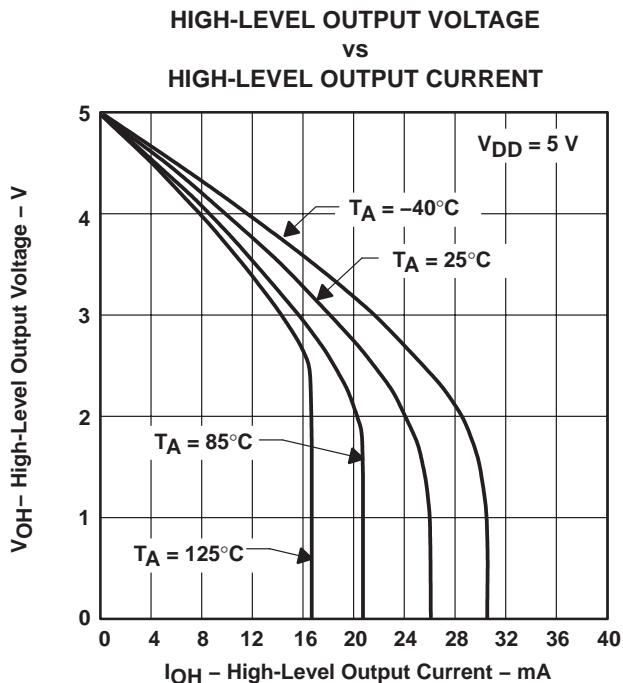


Figure 11

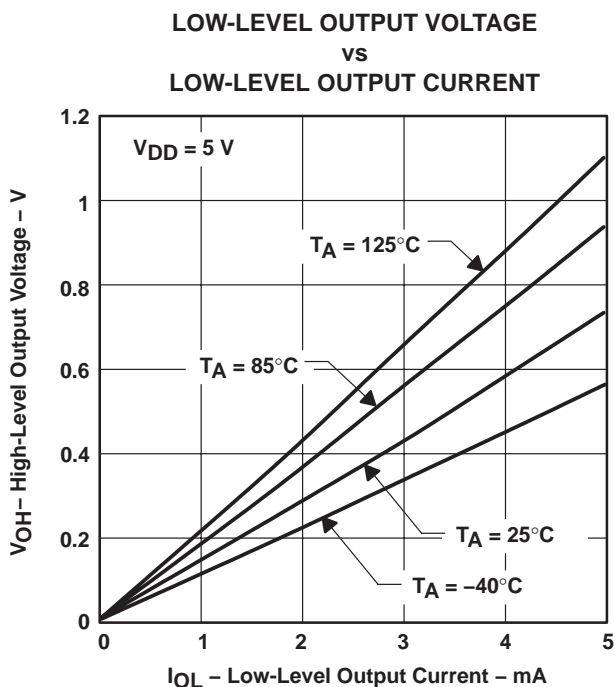


Figure 12

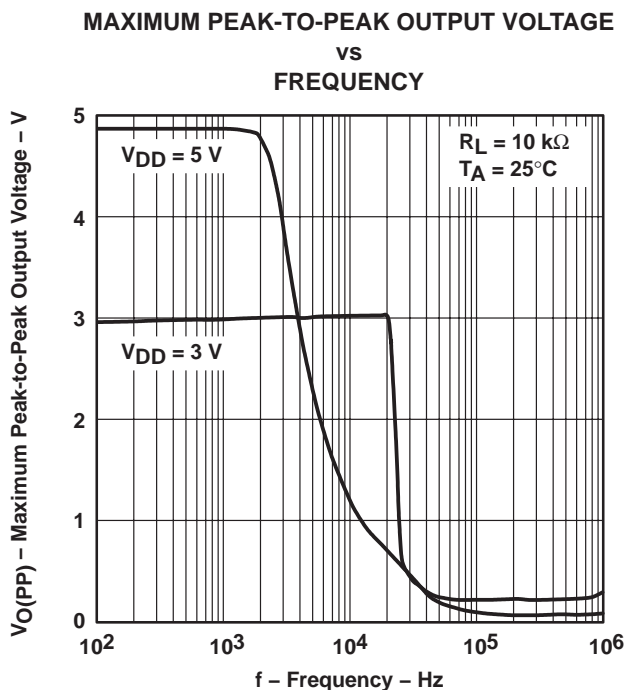


Figure 13

TLV2422-Q1, TLV2422A-Q1
Advanced LinCMOS™ RAIL-TO-RAIL OUTPUT
WIDE-INPUT-VOLTAGE MICROPOWER DUAL OPERATIONAL AMPLIFIERS

SGLS175 – AUGUST 2003

TYPICAL CHARACTERISTICS

SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE

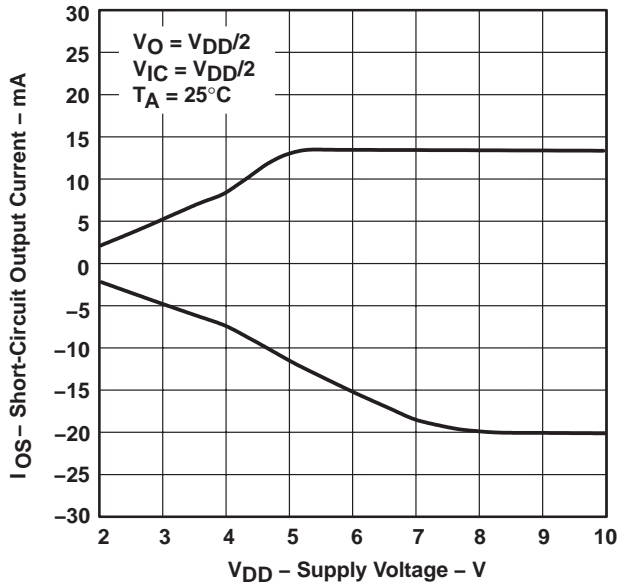


Figure 14

SHORT-CIRCUIT OUTPUT CURRENT
vs
FREE-AIR TEMPERATURE

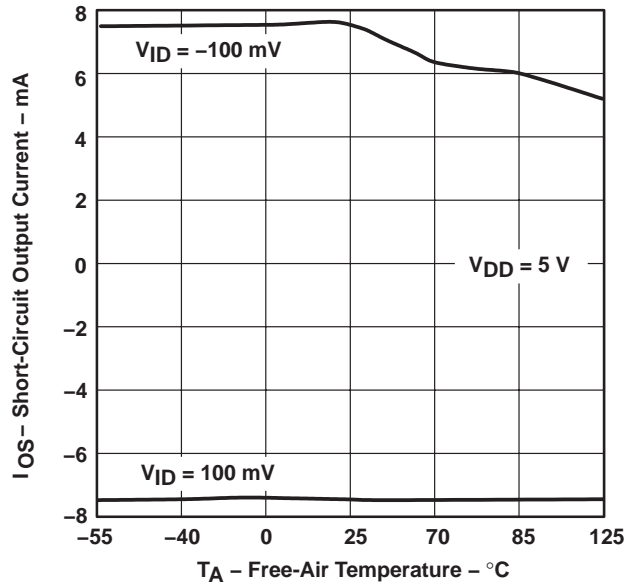


Figure 15

DIFFERENTIAL INPUT VOLTAGE
vs
OUTPUT VOLTAGE

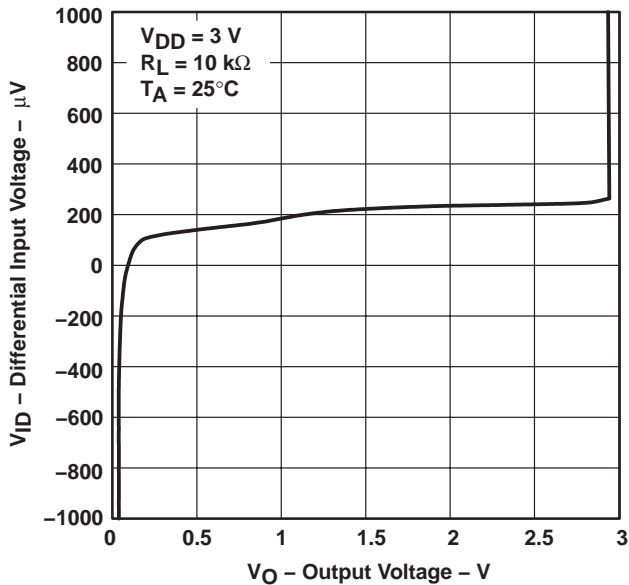


Figure 16

DIFFERENTIAL INPUT VOLTAGE
vs
OUTPUT VOLTAGE

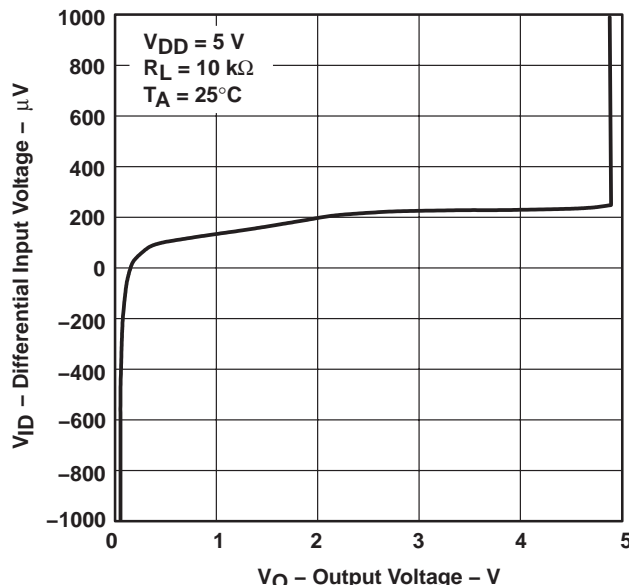


Figure 17



TYPICAL CHARACTERISTICS

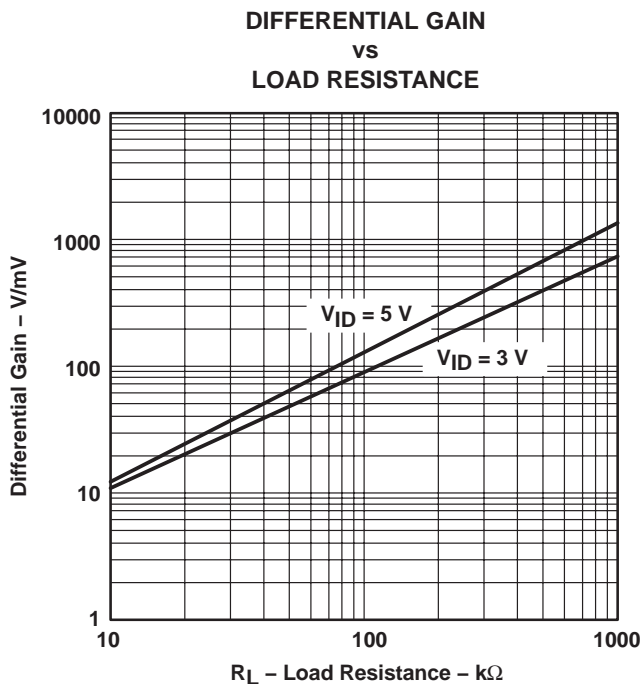


Figure 18

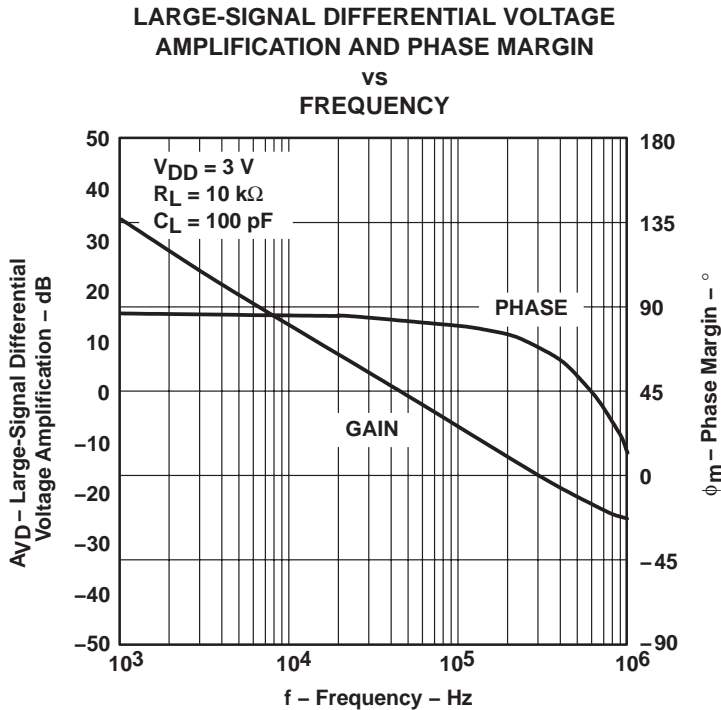


Figure 19

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN

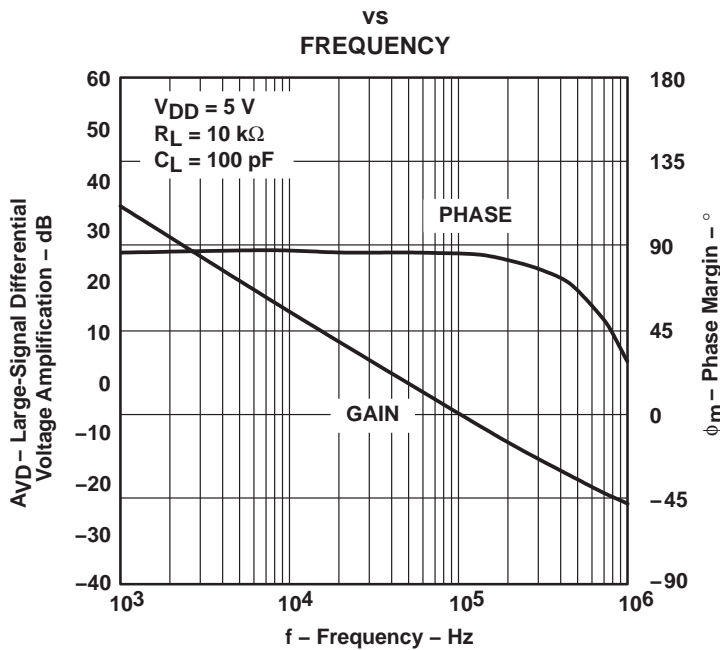


Figure 20

DIFFERENTIAL VOLTAGE AMPLIFICATION
 vs
FREE-AIR TEMPERATURE

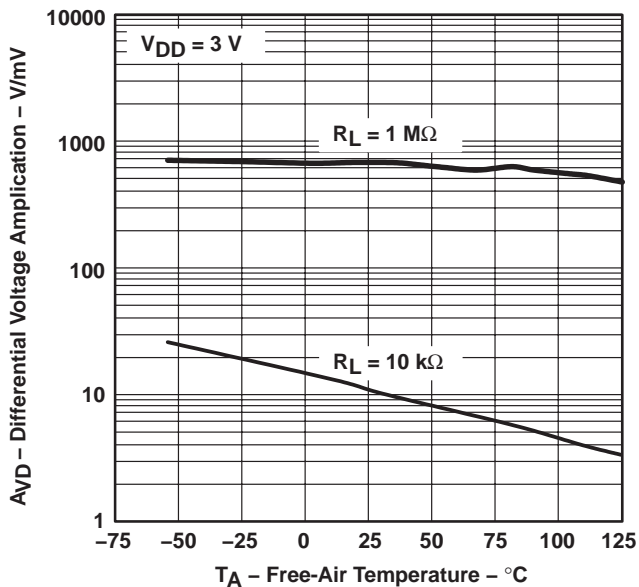


Figure 21

DIFFERENTIAL VOLTAGE AMPLIFICATION
 vs
FREE-AIR TEMPERATURE

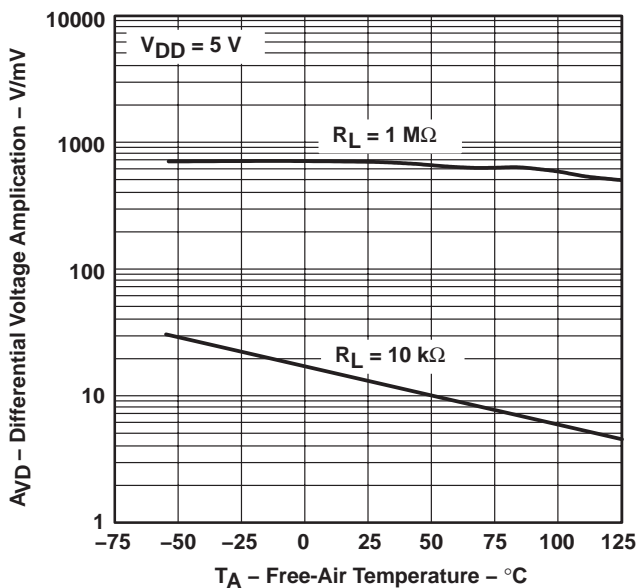


Figure 22

TYPICAL CHARACTERISTICS

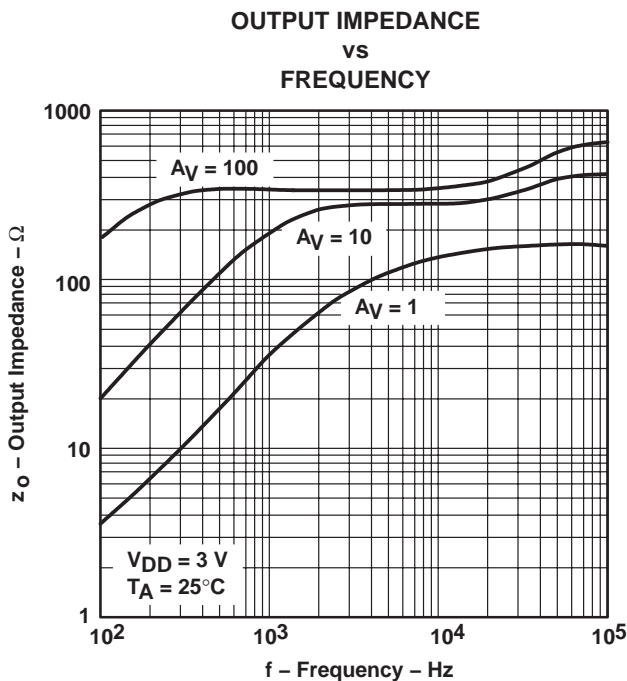


Figure 23

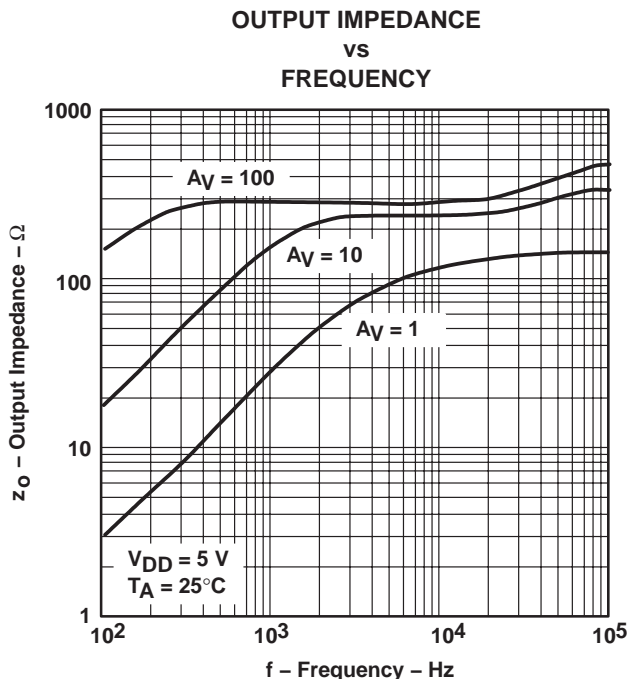


Figure 24

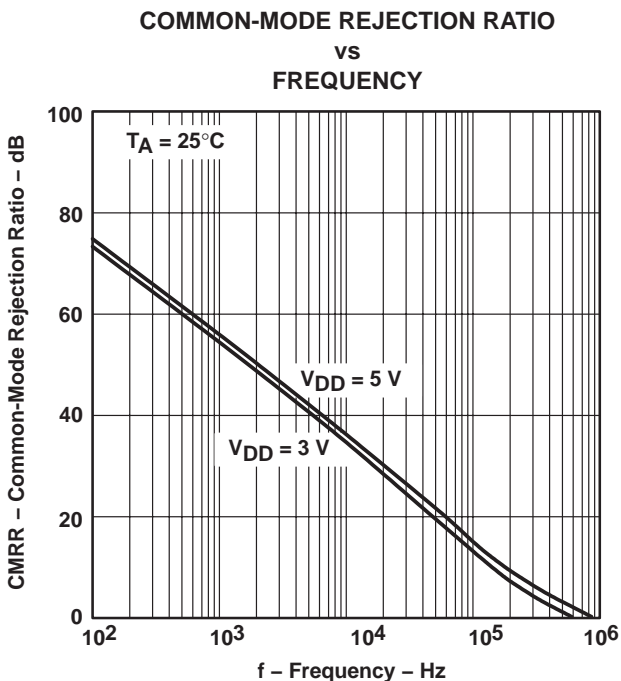


Figure 25

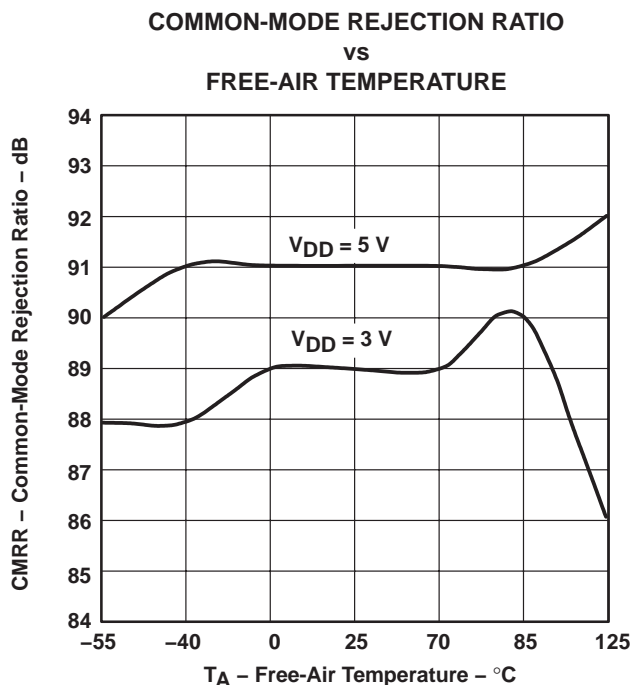


Figure 26

TYPICAL CHARACTERISTICS

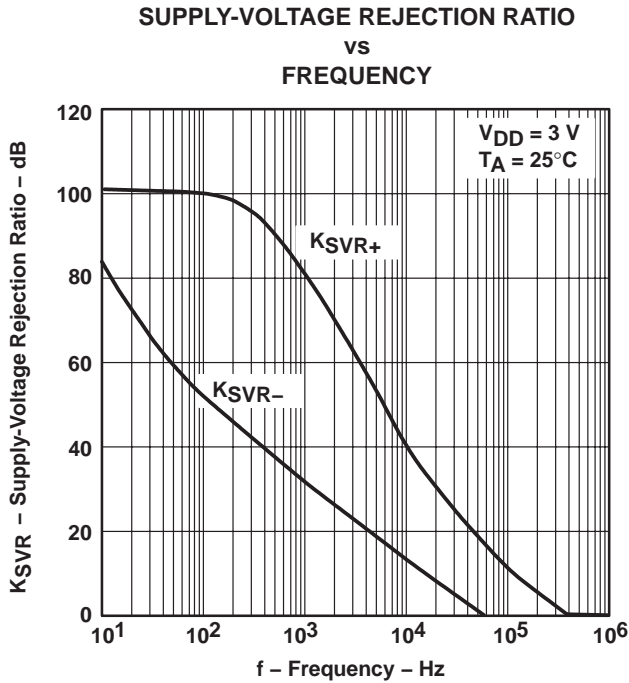


Figure 27

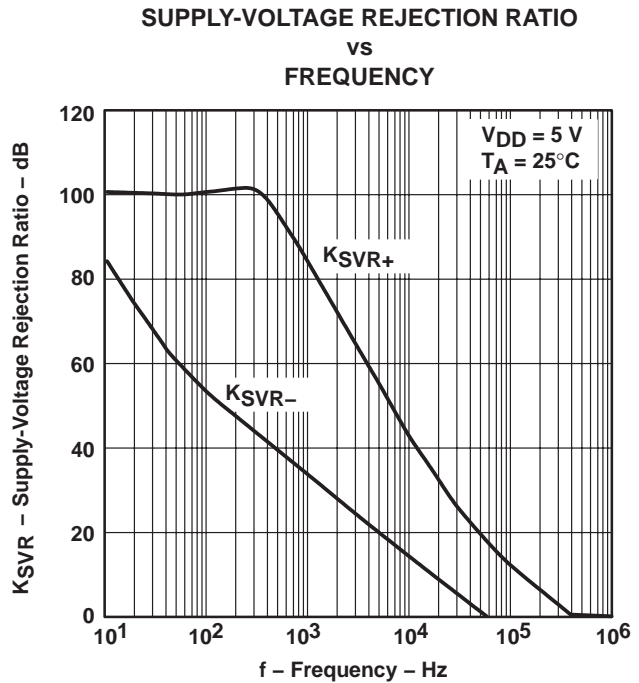


Figure 28

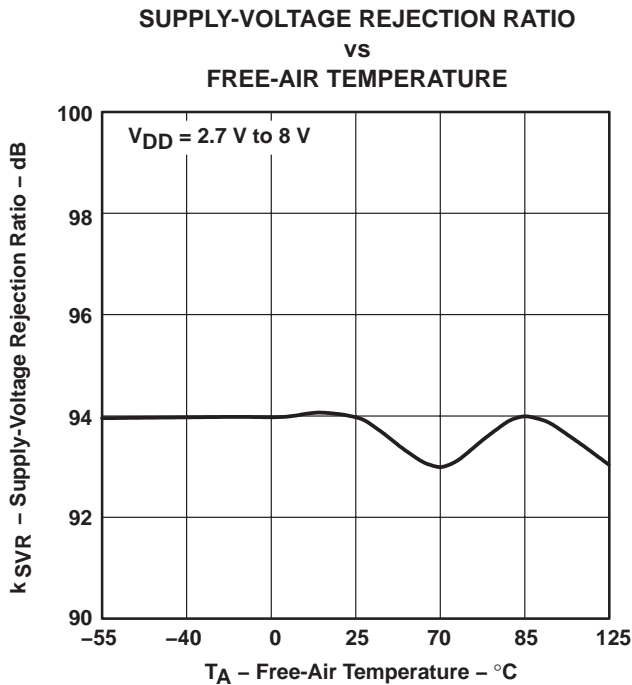


Figure 29

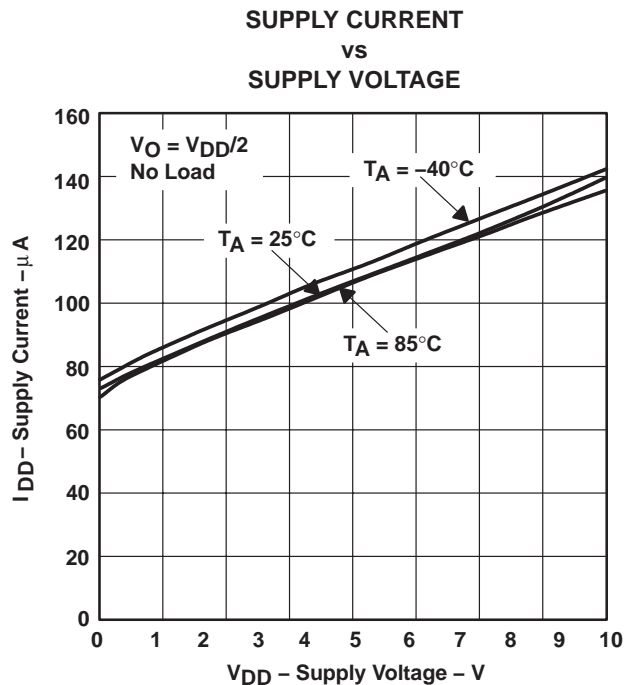
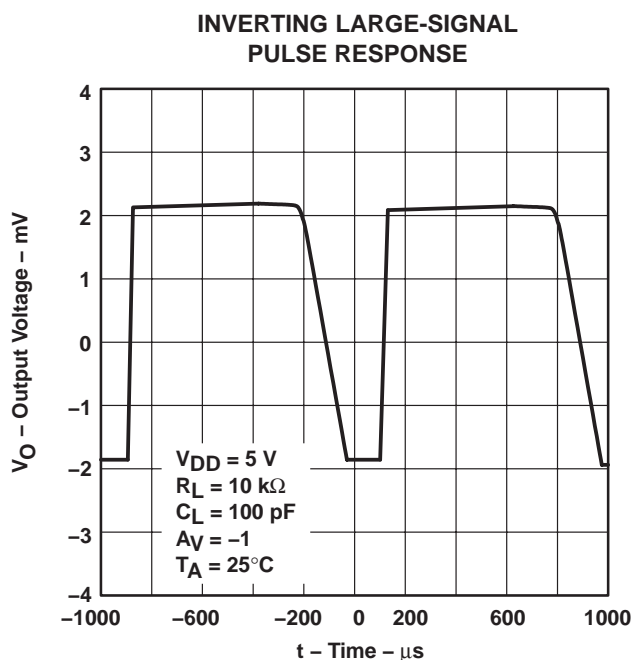
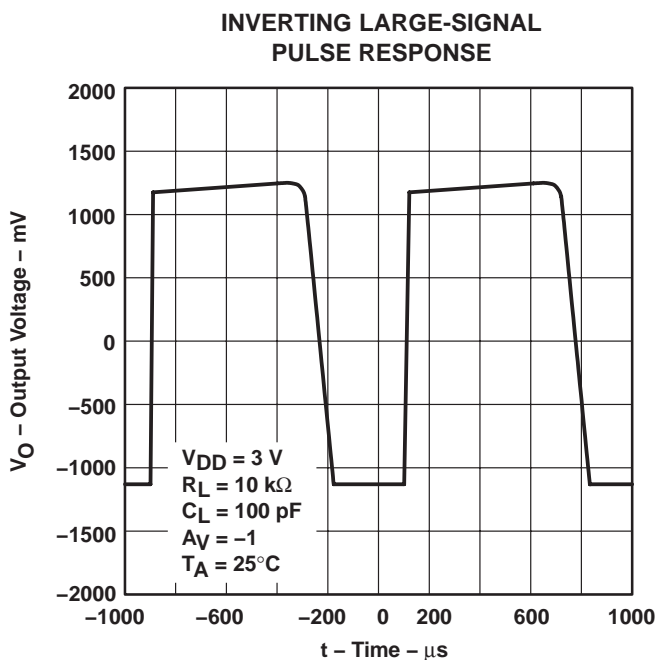
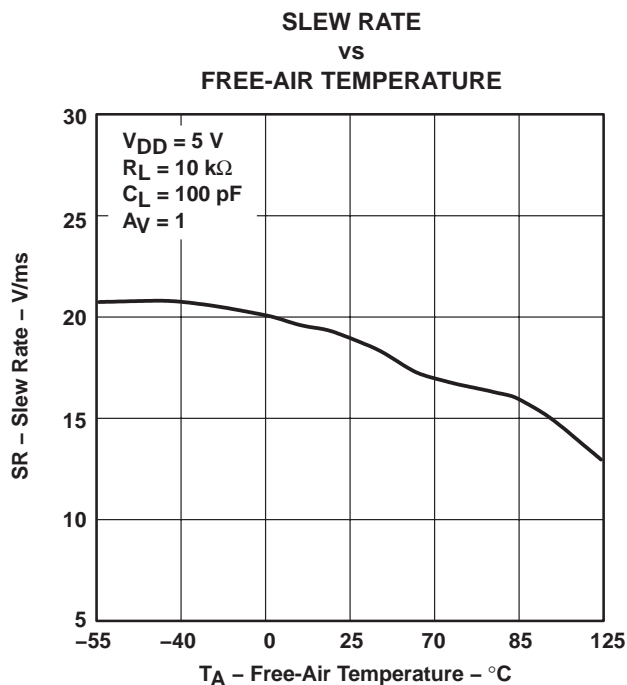
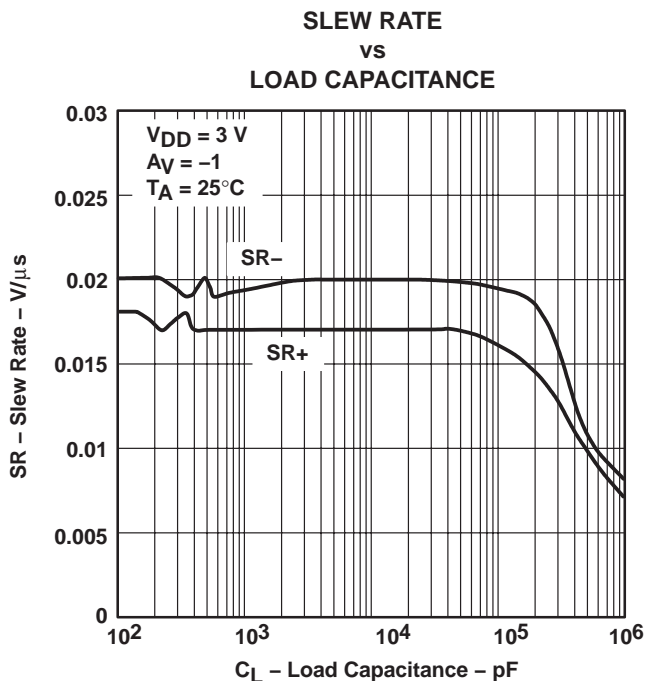


Figure 30

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

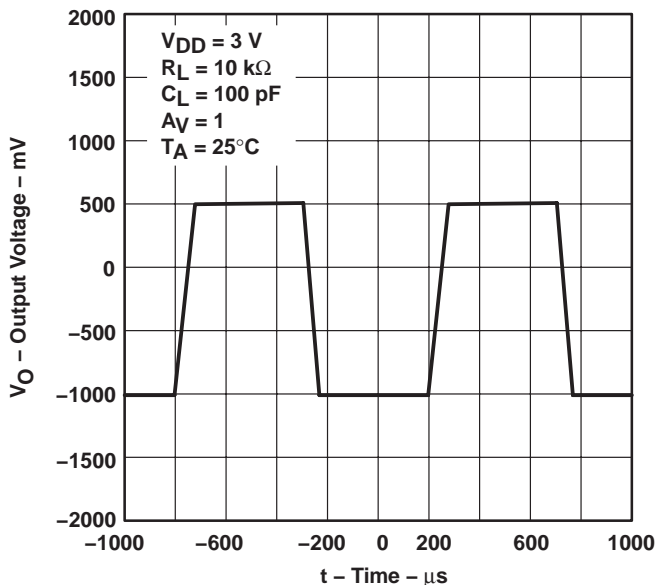


Figure 35

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

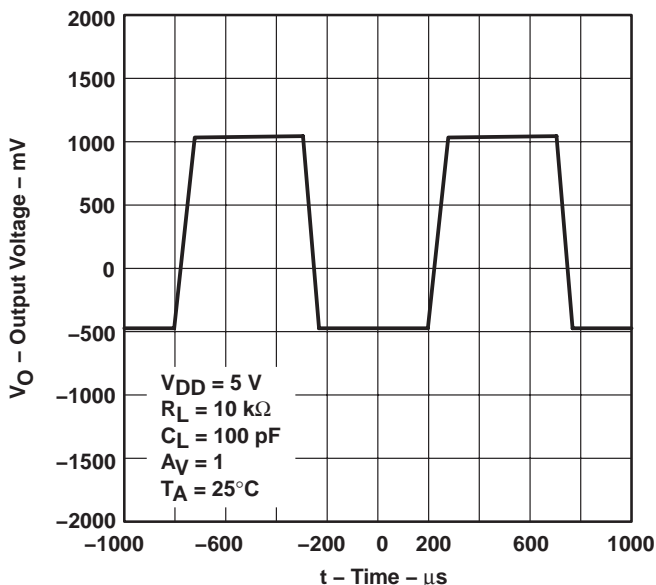


Figure 36

INVERTING SMALL-SIGNAL PULSE RESPONSE

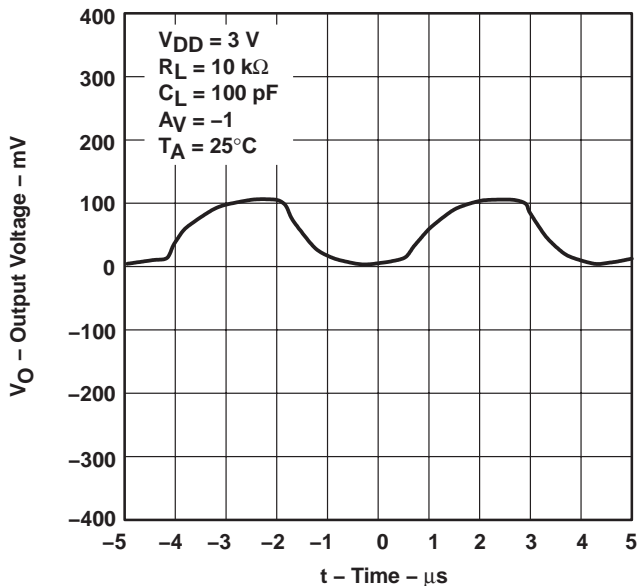


Figure 37

INVERTING SMALL-SIGNAL PULSE RESPONSE

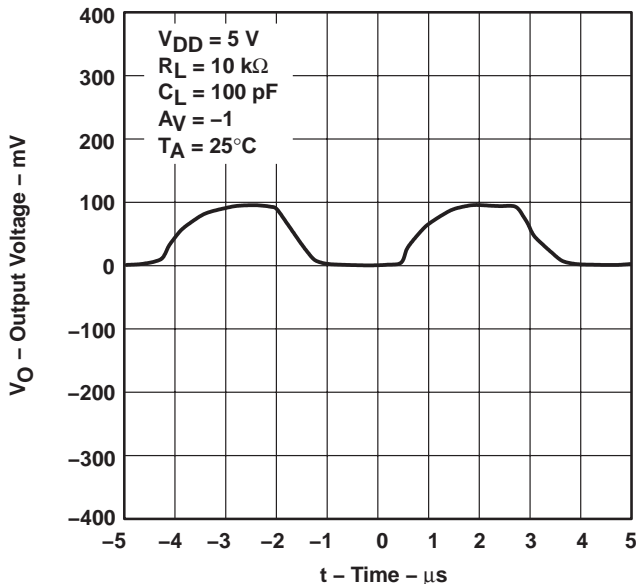


Figure 38

TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

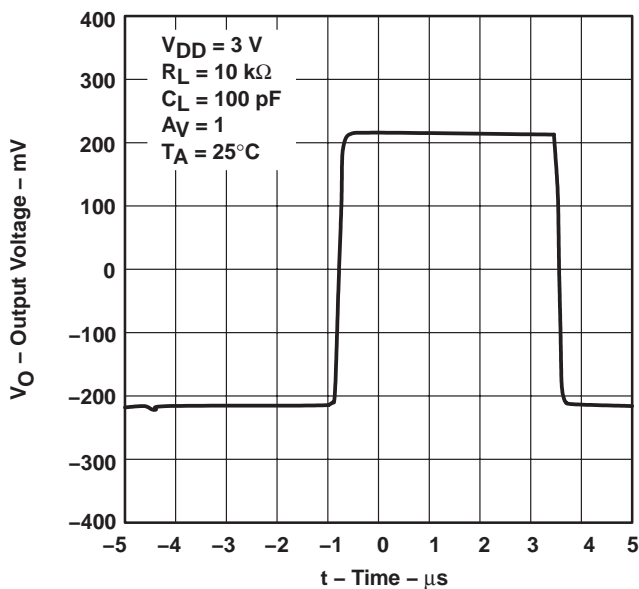


Figure 39

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

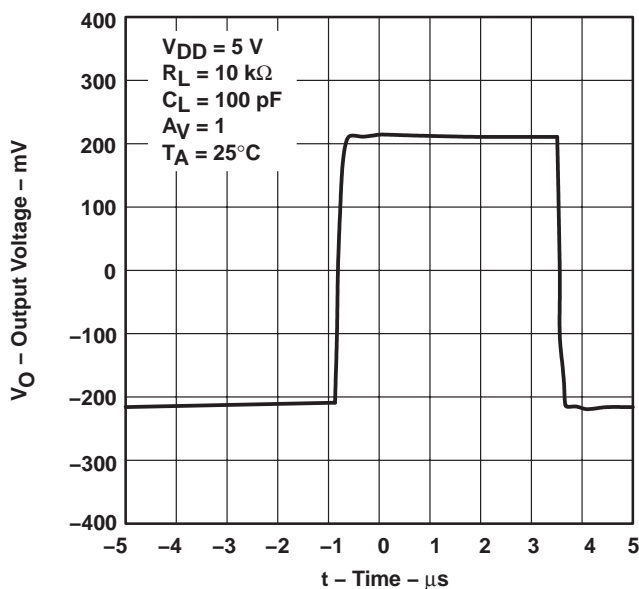


Figure 40

EQUIVALENT INPUT NOISE VOLTAGE VS FREQUENCY

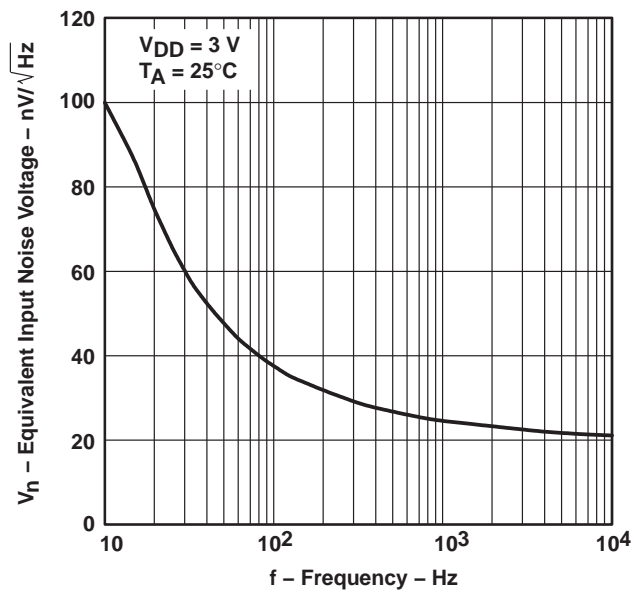


Figure 41

EQUIVALENT INPUT NOISE VOLTAGE VS FREQUENCY

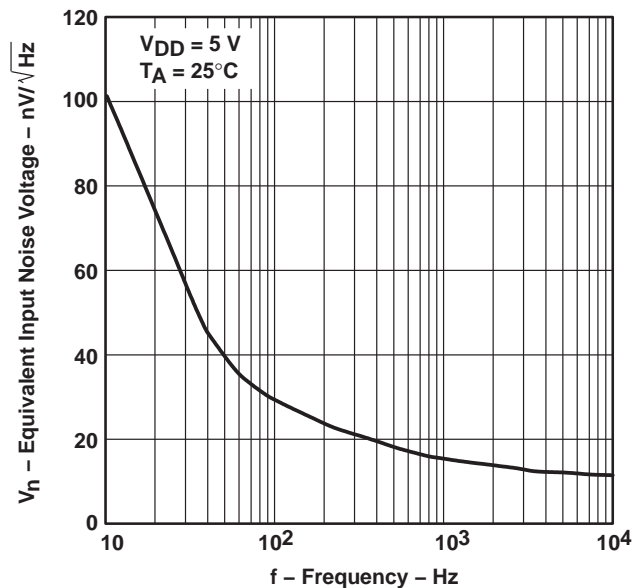


Figure 42

TYPICAL CHARACTERISTICS

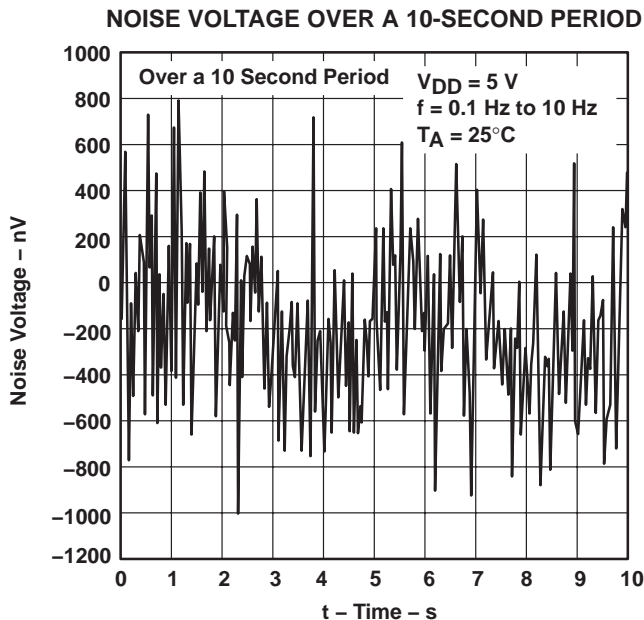


Figure 43

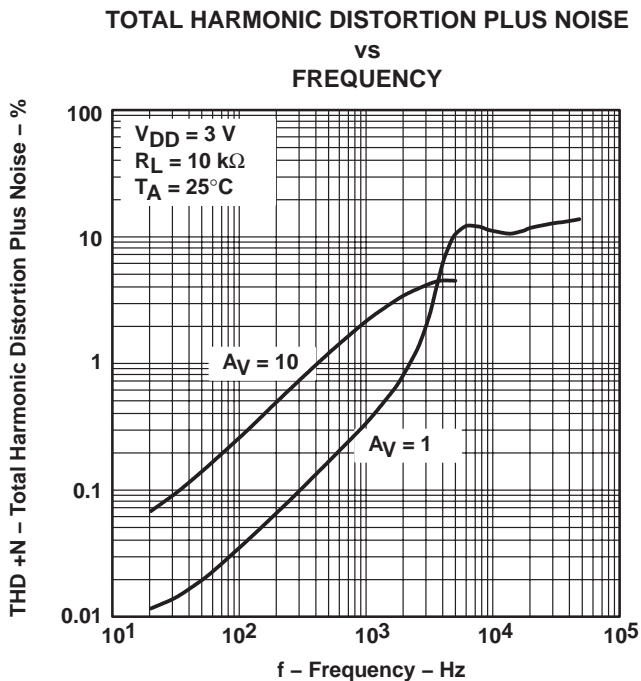


Figure 44

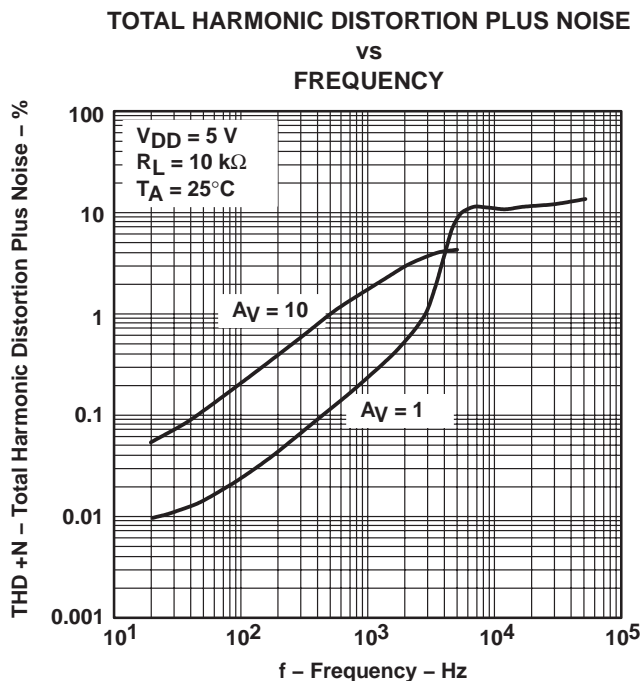


Figure 45

TYPICAL CHARACTERISTICS

**GAIN-BANDWIDTH PRODUCT
vs
SUPPLY VOLTAGE**

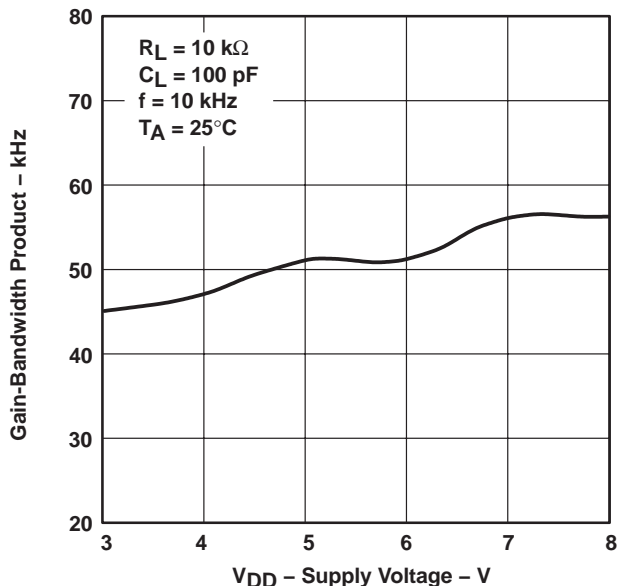


Figure 46

**GAIN-BANDWIDTH PRODUCT
vs
FREE-AIR TEMPERATURE**

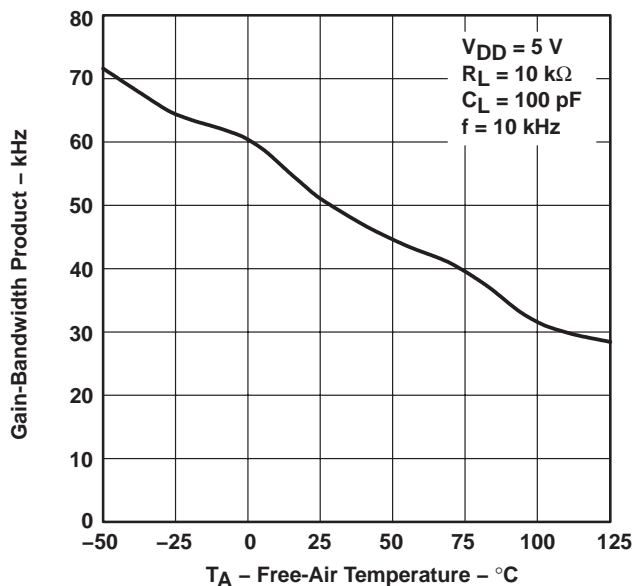


Figure 47

**PHASE MARGIN
vs
LOAD CAPACITANCE**

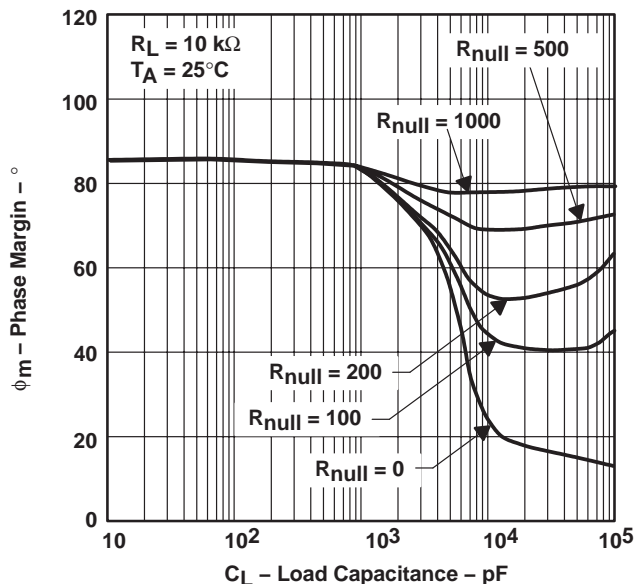


Figure 48

**GAIN MARGIN
vs
LOAD CAPACITANCE**

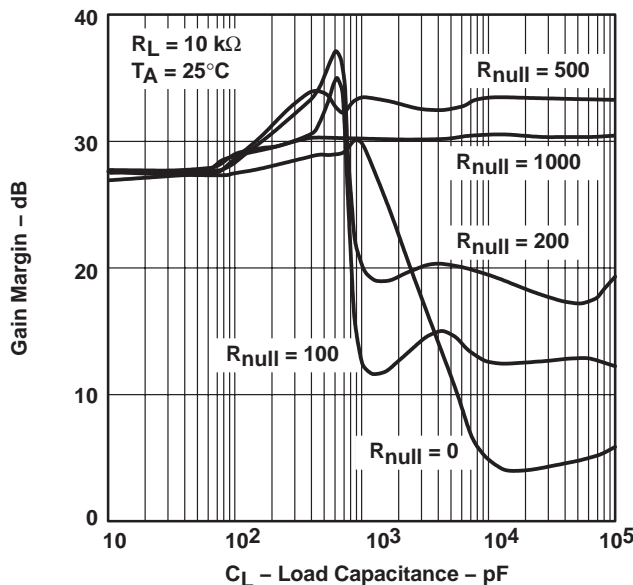


Figure 49

TYPICAL CHARACTERISTICS

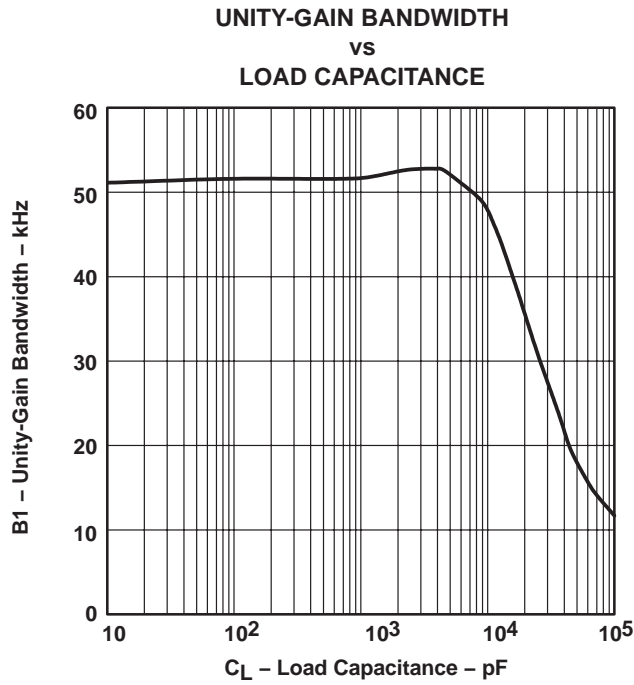


Figure 50

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TLV2422AQDRQ1	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
TLV2422QDRQ1	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

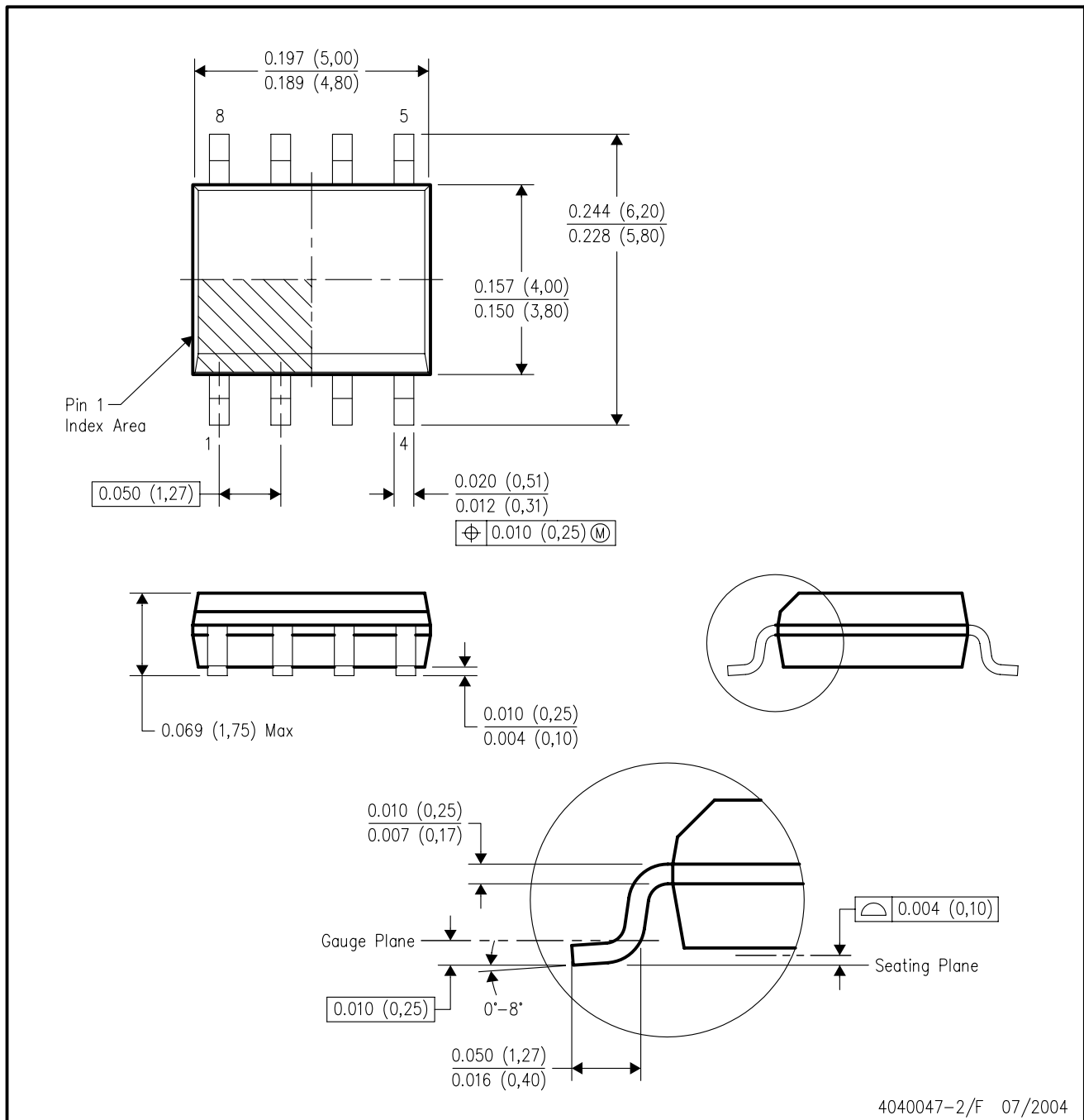
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-012 variation AA.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments
Post Office Box 655303 Dallas, Texas 75265